



2SA1013

PNP EPITAXIAL SILICON TRANSISTOR

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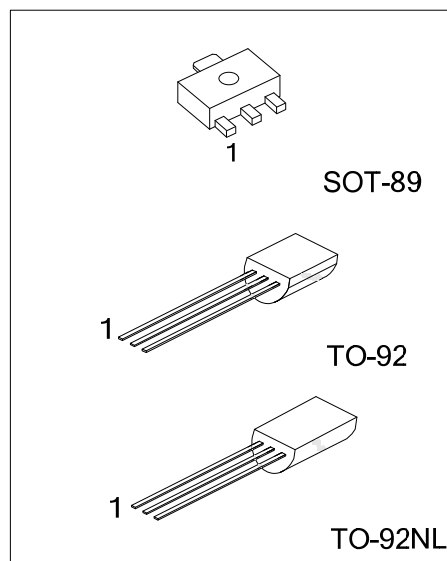
DESCRIPTION

The UTC **2SA1013** is a PNP epitaxial silicon transistor, it uses UTC's advanced technology to provide the customers with high BV_{CEO} and high DC current gain, etc.

The UTC **2SA1013** is suitable for power switching and color TV vertical deflection output, etc.

FEATURES

- * High BV_{CEO}
- * High DC current gain
- * Large continuous collector current capability



ORDERING INFORMATION

Ordering Number		Package	Pin assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SA1013L-x-AB3-R	2SA1013G-x-AB3-R	SOT-89	B	C	E	Tape Reel
2SA1013L-x-T92-B	2SA1013G-x-T92-B	TO-92	B	C	E	Tape Box
2SA1013L-x-T92-K	2SA1013G-x-T92-K	TO-92	B	C	E	Bulk
2SA1013L-x-T9N-B	2SA1013G-x-T9N-B	TO-92NL	B	C	E	Tape Box
2SA1013L-x-T9N-K	2SA1013G-x-T9N-K	TO-92NL	B	C	E	Bulk

2SA1013L-x-AB3-R	(1)Packing Type	(1) R: Tape Reel, B: Tape Box
	(2)Package Type	(2) AB3: SOT-89, T92: TO-92, T9N: TO-92NL
	(3)Rank	(3) refer to Classification of h_{FE}
	(4)Lead Free	(4) L: Lead Free, G: Halogen Free

■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	-160	V
Collector-Emitter Voltage		V_{CEO}	-160	V
Emitter-Base Voltage		V_{EBO}	-6	V
Collector Current		I_C	-1	A
Base Current		I_B	-0.5	A
Collector Power Dissipation	SOT-89	P_C	500	W
	TO-92/TO-92NL		900	W
Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.
Absolute maximum ratings are stress ratings only and functional device operation is not implied.

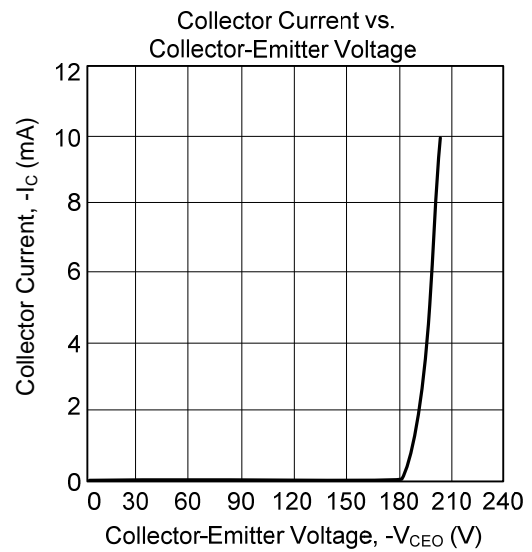
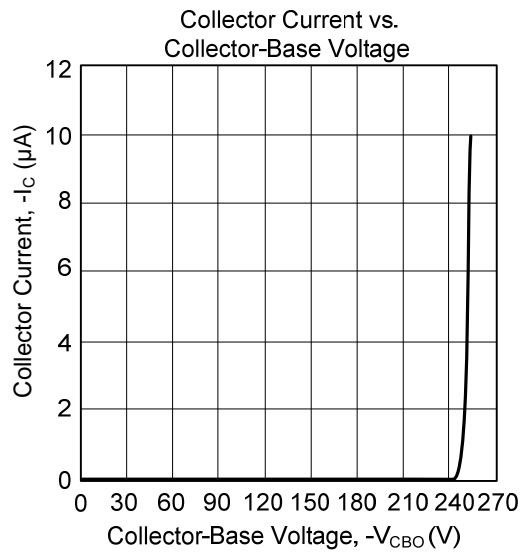
■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-150\text{V}, I_E=0$			-1.0	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=-6\text{V}, I_C=0$			-1.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-160			V
DC Current Gain	h_{FE}	$V_{CE}=-5\text{V}, I_C=-200\text{mA}$	60		320	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-500\text{mA}, I_B=-50\text{mA}$			-1.5	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-5\text{V}, I_C=-5\text{mA}$	-0.45		-0.75	V
Transition Frequency	f_T	$V_{CE}=-5\text{V}, I_C=-200\text{mA}$	15	50		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10\text{V}, f=1\text{MHz}, I_E=0$			35	pF

■ CLASSIFICATION OF h_{FE}

RANK	R	O	P
RANGE	60~120	100~200	160~320

■ TYPICAL CHARACTERISTICS



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